

## SAM™ Data Sheet SAM-980-50-500fs-x, λ = 980 nm

Laser wavelength	$\lambda = 980 \text{ nm}$
High reflection band	λ = 930 1020 nm
Absorbance	$A_0 = 50 \%$
Modulation depth	∆R = 30 %
Non-saturable loss	A <sub>ns</sub> = 20 %
Saturation fluence	$\Phi_{sat}$ = 60 µJ/cm <sup>2</sup>
Relaxation time constant	τ ~ 500 fs
Damage threshold	$\Phi_{sat}$ = 900 µJ/cm <sup>2</sup>
Chip area	4.0 mm x 4.0 mm; other dimensions on request
Chip thickness	450 μm
Protection	the SAM is protected with a dielectric front layer
Mounting option x denotes the type of mounting as follows: x = 0 unmounted $x = 12.7$ g unmounted uncover with 12.7 mm $\oslash$	

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## Low intensity spectral reflectance

